



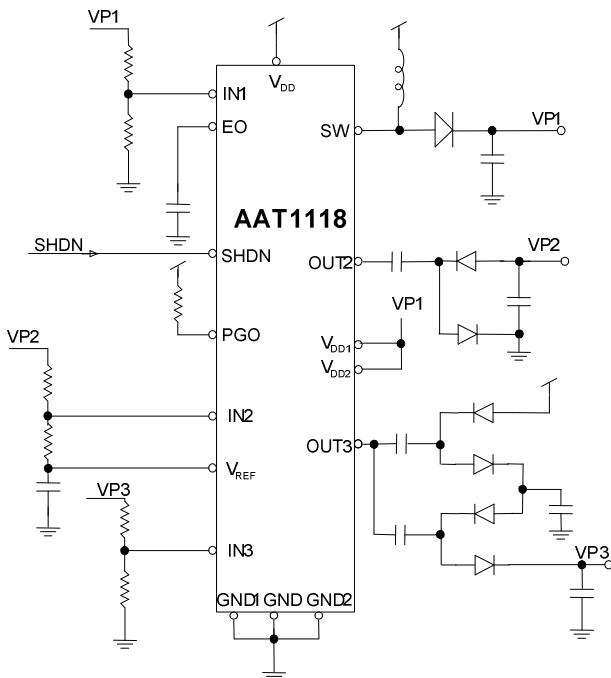
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Adjustable Triple-Channel TFT LCD DC-DC Converter

FEATURES

- Built in 1.6A, 0.2Ω Switching NMOS
- Fault and Thermal Protection
- Internal Soft-Start Function
- Internal Power Up Sequencing
- Dual Adjustable Charge Pump Output
Positive Output to 40V
Negative Output to -40V
- Power Good Output
- TSSOP-16 Package

TYPICAL APPLICATION



GENERAL DESCRIPTION

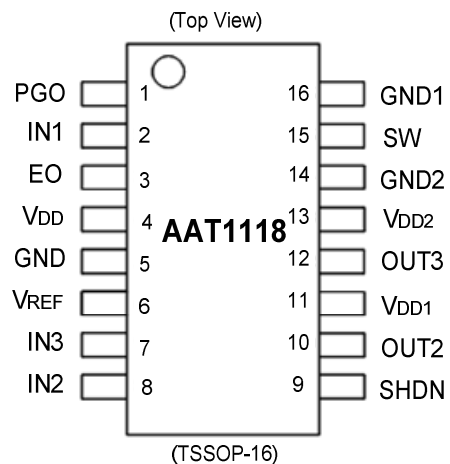
The AAT1118 is an adjustable triple-channel TFT LCD DC-DC converter that provides one current mode PWM, one positive charge pump and one negative charge pump. Built-in functions include soft-start and power up sequencing. When power is turned on, soft-start avoids inrush current. Power up sequencing feature provides compensation for LCD panel to maintain a smooth voltage during a turn-on cycle.

The DC-DC converter consists of an on-chip voltage reference, error amplifier, current sense, pulse width modulation controller, under-voltage lockout protection, thermal detect, soft-start, and fault protection circuit.

When the two charge pumps are in operation, the output voltage would be doubled and the generated VP3 and VP2 could switch on or off TFT gate.

With the minimal external components, the AAT1118 offers a simple and economical solution for TFT LCD power.

PIN CONFIGURATION





AAT1118

ORDERING INFORMATION

DEVICE TYPE	PART NUMBER	PACKAGE	PACKING	TEMP. RANGE	MARKING	MARKING DESCRIPTION
AAT1118	AAT1118-T1-T	T1:TSSOP16	T: Tape and reel	-40 °C to +85 °C	AAT1118 XXXXXX	1. Part Name 2. Lot No. (6~9 Digits)

NOTE: All AAT Products are Lead Free and Halogen Free.

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
V _{DD} to GND	V _{DD}	7	V
SW to GND	V _{SW}	18	V
V _{DD1} , V _{DD2} to GND	V _{DDH}	16	V
Input Voltage 1 (IN1, IN2, IN3, SHDN)	V _{I1}	V _{DD} +0.3	V
Output Voltage 1 (EO, V _{REF})	V _{O1}	V _{DD} +0.3	V
Output Voltage 2 (OUT2, OUT3, SW, PGO)	V _{O2}	V _{DDH} +0.3	V
Operating Free-Air Temperature Range	T _C	-40 °C to +85 °C	°C
Storage Temperature Range	T _{storage}	-45 °C to °C +125	°C
Power Dissipation	P _d	750	mW



ELECTRICAL CHARACTERISTICS

($V_{DD} = 3.3V$, $V_{DDH} = 10V$)

Operating Power

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Input Supply Voltage Range	V_{DD}		2.6		5.5	V
V_{DD} Under Voltage Lockout	V_{UVLO}	Falling	2.1	2.2	2.3	V
		Rising	2.3	2.4	2.5	V
Regulated Output Voltage Range	V_{P1}		6		14	V
Quiescent Current	I_{VDD}	$V_{IN1} = 1.3V$, not Switching		0.5	0.8	mA
		$V_{IN1} = 1.1V$, Switching		3	6	mA
Shutdown Current	I_{SHDN}	$V_{SHDN} = GND$		0.1	10.0	μA
Thermal Shutdown				160		$^{\circ}C$

Reference Voltage

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Reference Voltage	V_{REF}	$I_{VREF} = 100\mu A$	1.238	1.250	1.262	V
Line Regulation	V_{RI}	$I_{VREF} = 100\mu A$, $V_{DD} = 2.5V \sim 5V$	-	2	5	mV
Load Regulation	V_{RO}	$I_{VREF} = 0 \sim 100\mu A$	-	1	5	mV

EA (Error Amplifier)

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Feedback Voltage	V_{IN1}	Level to Produce $V_{EO} = 1.24V$	1.238	1.250	1.262	V
Input Bias Current	I_{B1}	$V_{IN1} = 1.24V$		0	40	nA
Feedback-Voltage Line Regulation	V_{RI}	Level to Produce $V_{EO} = 1.24V$ $2.6V < V_{DD} < 5.5V$		0.05	0.15	%/V
Transconductance	G_m	$\Delta I = 5\mu A$	70	105	240	$\mu A/V$
Voltage Gain	A_V			1,500		V/V
Fault Detect Trigger Voltage	V_{FI}		1.07	1.10	1.14	V

**AAT1118****Oscillator**

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Oscillation Frequency	f_{OSC}		1,100	1,320	1,600	kHz
Maximum Duty Cycle	D_{MAX}		79	85	92	%

N-Channel Switch

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Current Limit	I_{LIM}		1.1	1.6	2.1	A
On-Resistance	R_{ON}	$I_{SW} = 1.2A$		0.28	0.50	Ω
Leakage Current	I_{SWOFF}	$V_{SW} = 12V$		0.01	20.00	μA

Control Inputs Characteristics

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Input Low Voltage	V_{IL}				0.3 V_{DD}	V
Input High Voltage	V_{IH}		0.7 V_{DD}			V
Hysteresis	V_{HYS}			0.1 V_{DD}		V
SHDN Pull Up Current	I_{PH}			0.001	1.000	μA

Soft Start & Fault Detect Time

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Channel 1 Soft Start Time	t_{SS1}			14		ms
Channel 2 Soft Start Time	t_{SS2}			3.5		ms
Channel 3 Soft Start Time	t_{SS3}			3.5		ms
During Fault Protect Trigger Time	t_{FP}			83		ms
IN1 Fault Protection Voltage	V_{F1}		1.05	1.10	1.15	V
IN2 Fault Protection Voltage	V_{F2}		0.08	0.13	0.18	V
IN3 Fault Protection Voltage	V_{F3}		1.05	1.10	1.15	V



ELECTRICAL CHARACTERISTICS

($V_{DD} = 3.3V$, $V_{DDH} = 10V$)

Charge Pump Regulator Characteristics

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
V_{DD1} Input Supply Range	V_{DD1}		6		15	V
V_{DD2} Input Supply Range	V_{DD2}		6		15	V
IN2 Threshold Voltage	IN2		-50	0	50	mV
IN3 Threshold Voltage	IN3		1.20	1.25	1.30	V
IN2 Input Bias Current	I_{B2}	$V_{IN2} = -0.05V$	-50		50	nA
IN3 Input Bias Current	I_{B3}	$V_{IN3} = -1.5V$	-50		50	nA
Charge Pump Frequency	f_{OSCP}		540	640	740	kHz
OUT2 Switch R-on	R_{ONP2}			3	20	Ω
	R_{ONN2}			3	20	Ω
OUT3 Switch R-on	R_{ONP3}			3	20	Ω
	R_{ONN3}			3	20	Ω
Continuous Output Current	I_{OUT}				30	mA



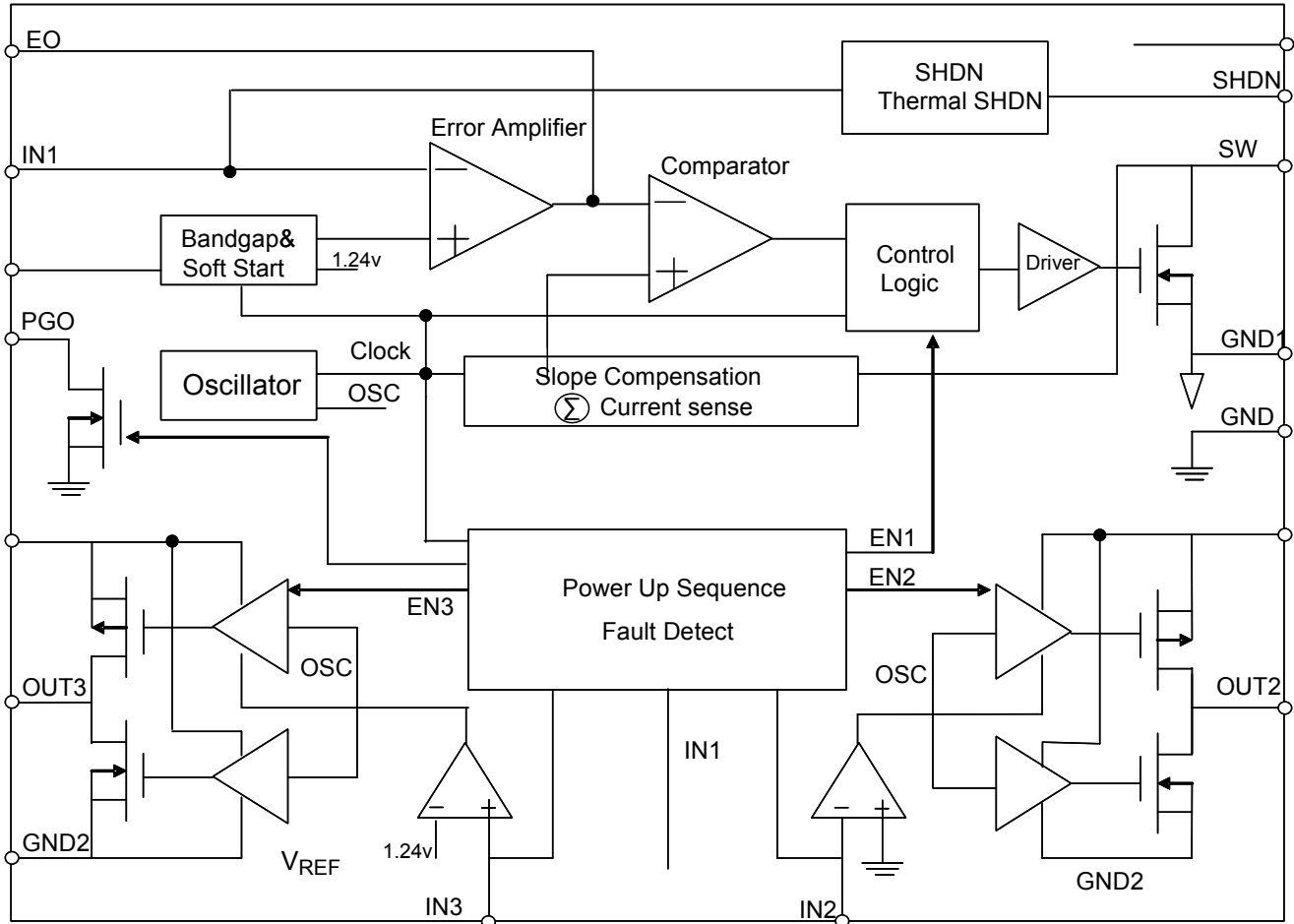
PIN DESCRIPTION

PIN NO.	NAME	I/O	DESCRIPTION
1	PGO	O	HV Switch Output
2	IN1	I	Inverting Input Pin of PWM Error Amplifier
3	EO	I	Output Pin of PWM Error Amplifier
4	V _{DD}	-	Power Supply
5	GND	-	Ground
6	V _{REF}	O	Reference Voltage Output
7	IN3	I	Charge Pump Channel 3 Feedback Input
8	IN2	I	Charge Pump Channel 2 Feedback Input
9	SHDN	I	Shutdown Control Pin; High for Enable
10	OUT2	O	Charge Pump Channel 2 Output
11	V _{DD1}	-	High Voltage Power Supply
12	OUT3	O	Charge Pump Channel 3 Output
13	V _{DD2}	-	High Voltage Power Supply
14	GND2	-	Ground
15	SW	O	Switch Pin
16	GND1	-	SW MOS Ground



FUNCTION BLOCK DIAGRAM

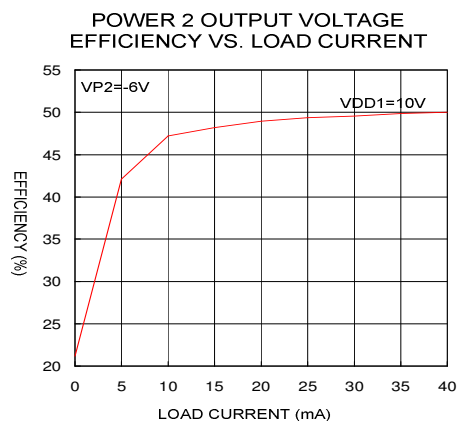
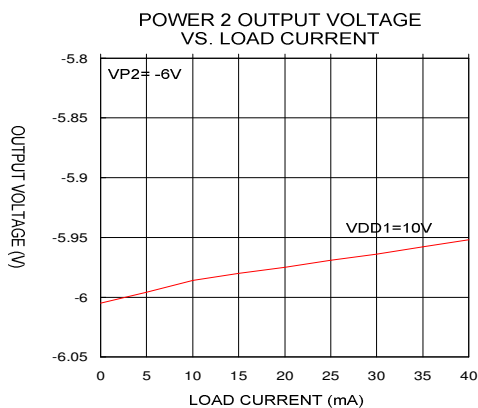
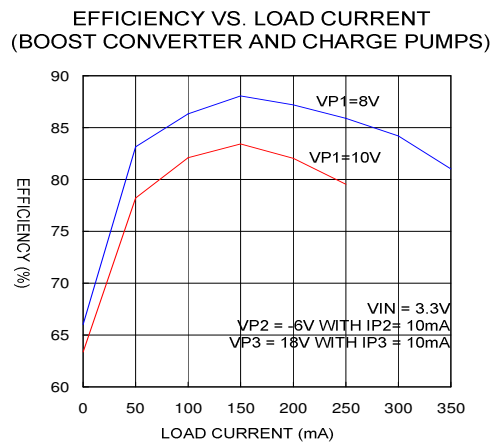
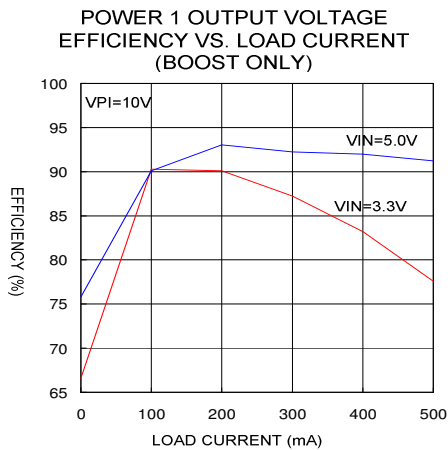
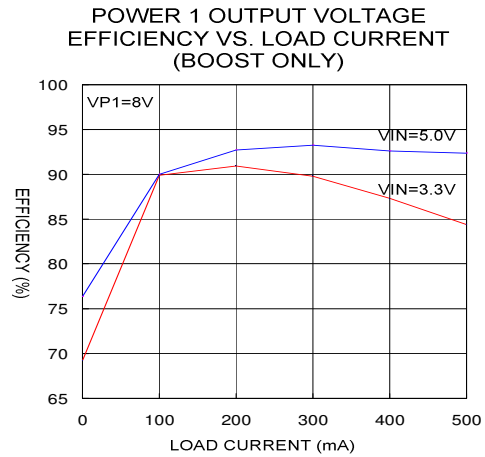
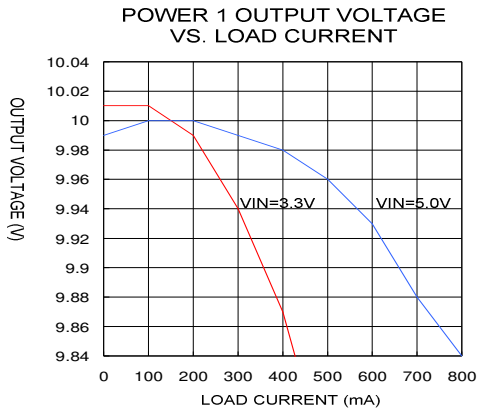
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TYPICAL OPERATING CHARACTERISTICS

($V_{IN} = 3.3V$, $T_C = +25^\circ C$, Unless Otherwise Noted.)

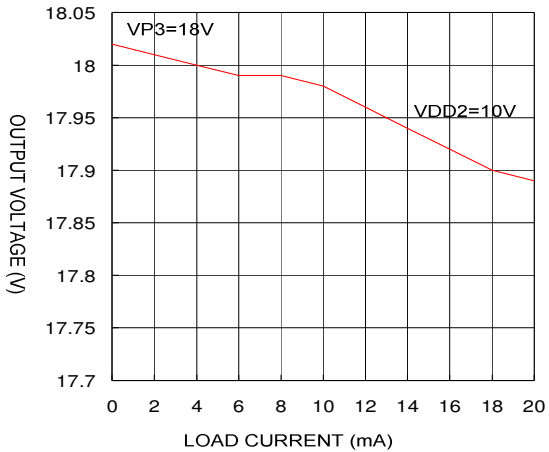




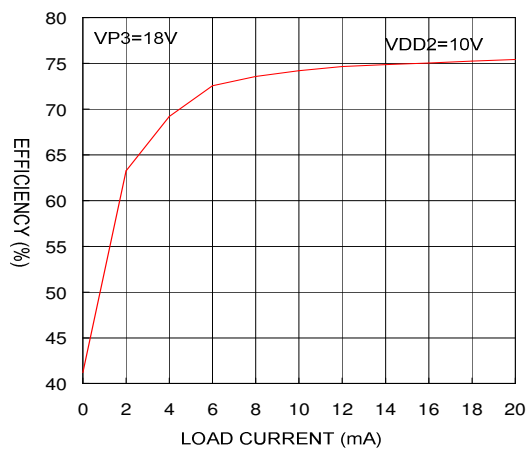
TYPICAL OPERATING CHARACTERISTICS (CONT.)

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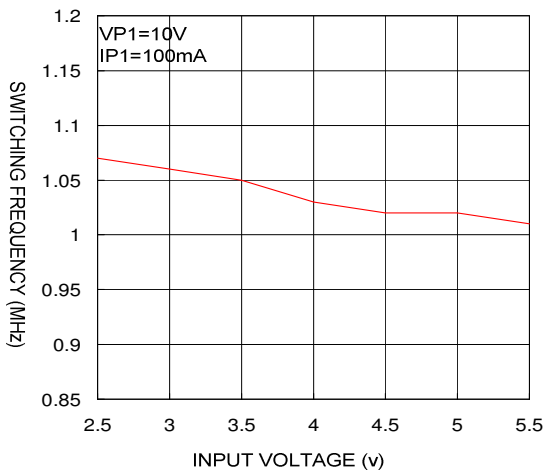
POWER 3 OUTPUT VOLTAGE VS. LOAD CURRENT



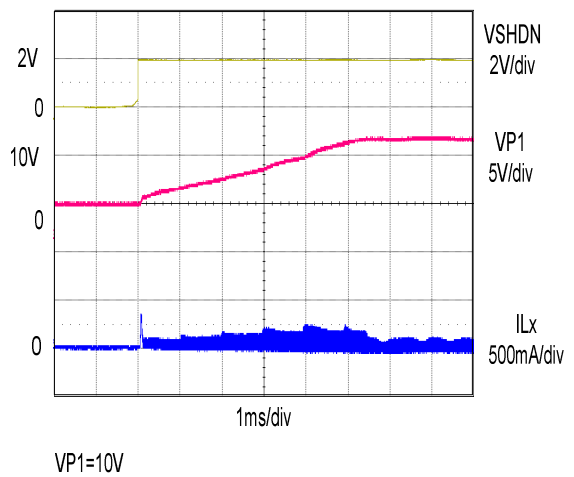
POWER 3 OUTPUT VOLTAGE EFFICIENCY VS. LOAD CURRENT



SWITCHING FREQUENCY VS. INPUT VOLTAGE



POWER 1 OUTPUT VOLTAGE START UP WAVEFORM

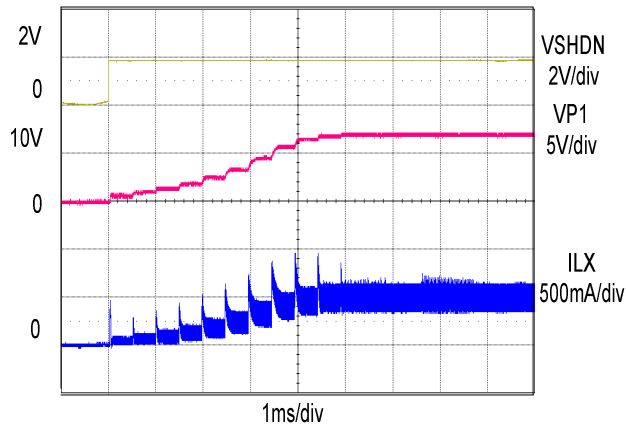




TYPICAL OPERATING CHARACTERISTICS (CONT.)

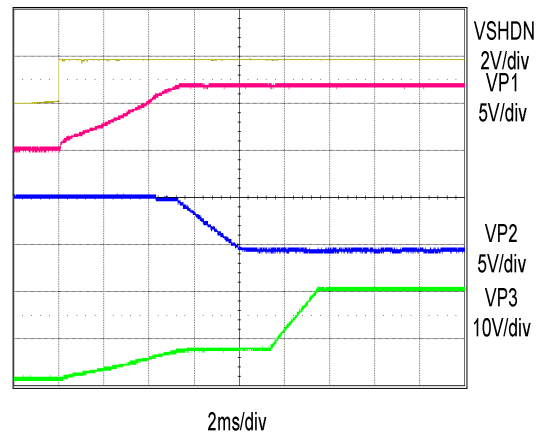
($V_{IN} = 3.3V$, $T_C = +25^\circ C$, Unless Otherwise Noted.)

POWER 1 OUTPUT VOLTAGE WAVEFORM WITH LOAD



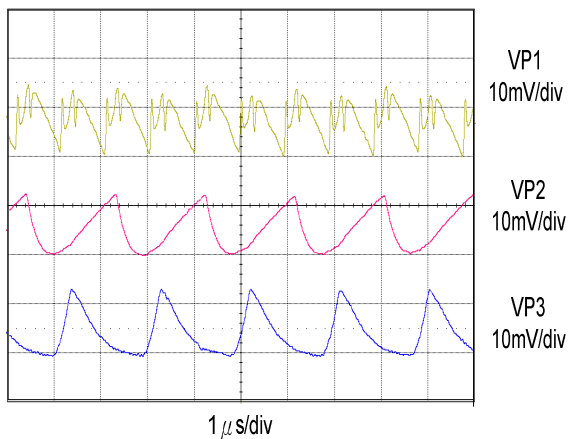
VP1=10V, IP1=200mA

POWER ON SEQUENCING AAT1118



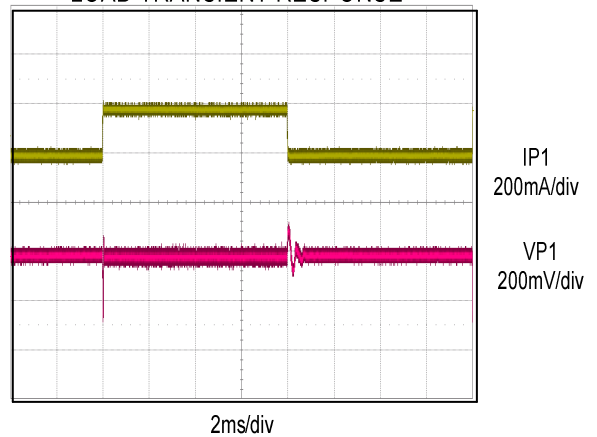
VP1=10V, VP2=-6V, VP3=18V

OUTPUT RIPPLE WAVEFORM



VP1=10V, IP1=200mA
VP2=-6V, IP2=10mA
VP3=18V, IP3=10mA

LOAD TRANSIENT RESPONSE

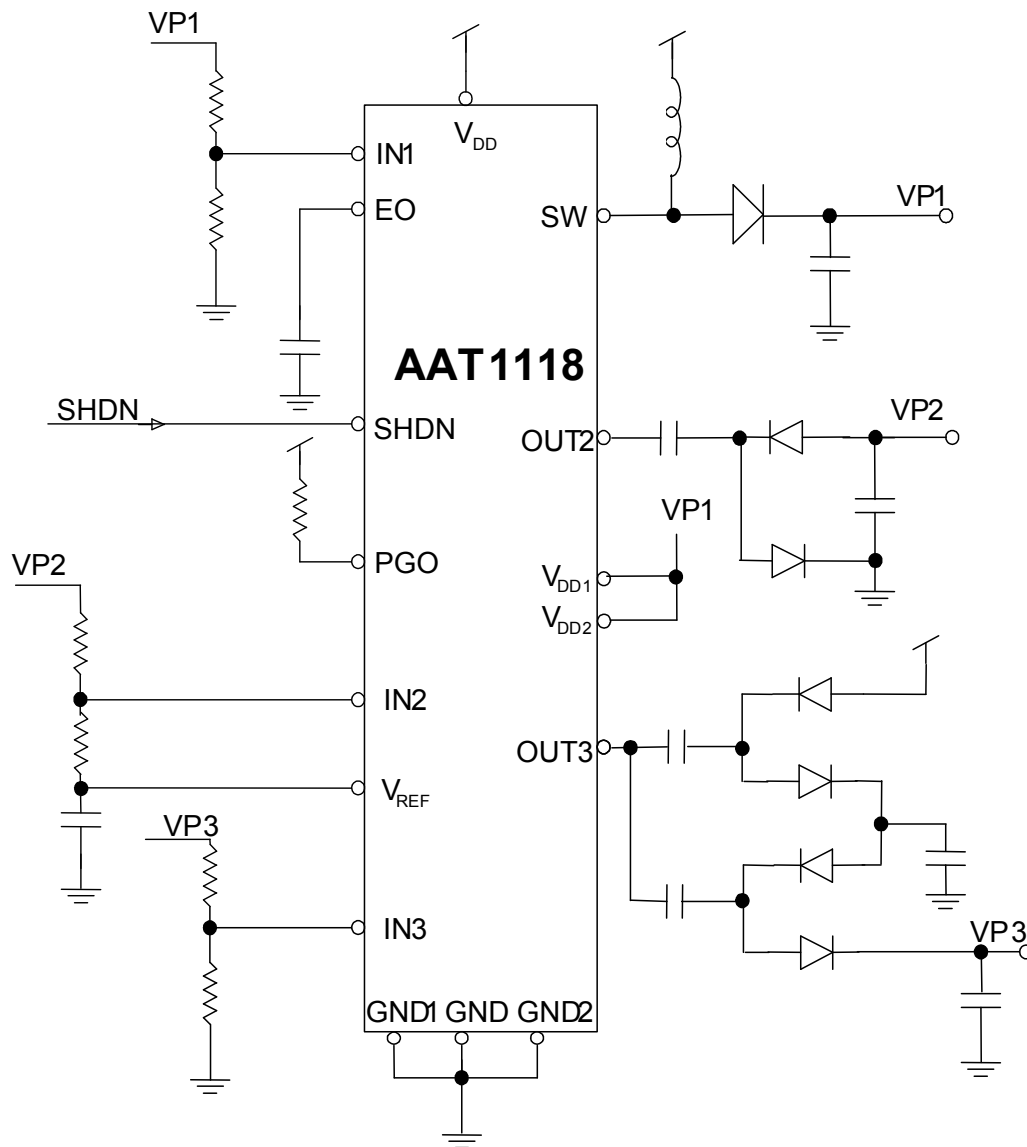


$V_{IN} = 3.3V$, VP1=10V
IP1 (20mA TO 200mA)



TYPICAL APPLICATION CIRCUIT

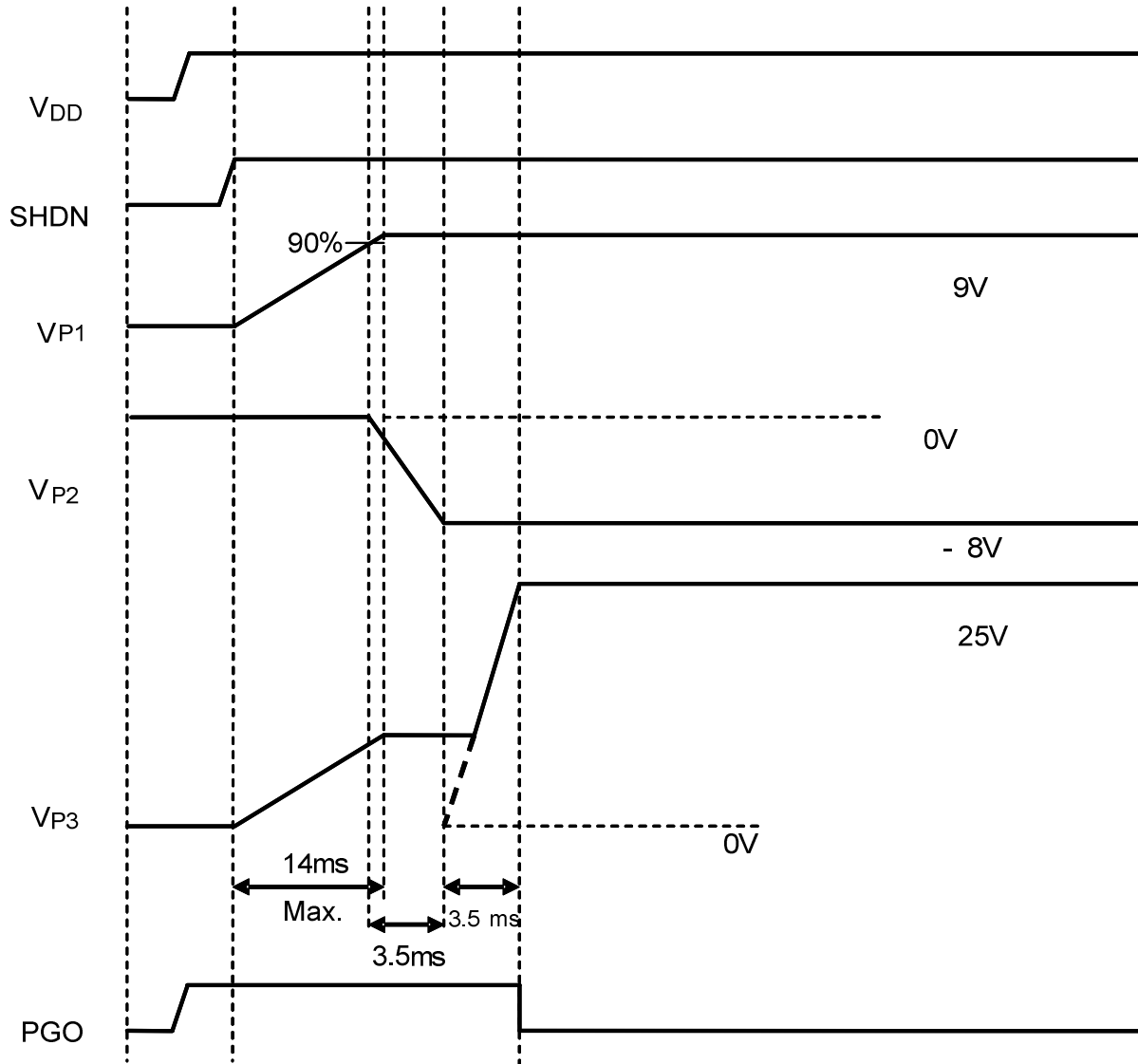
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TIMING CHART

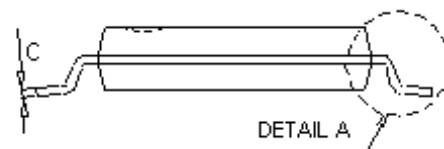
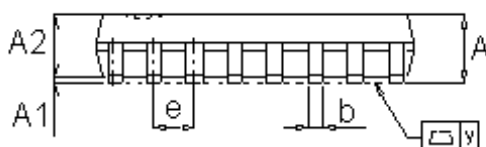
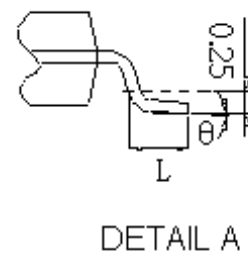
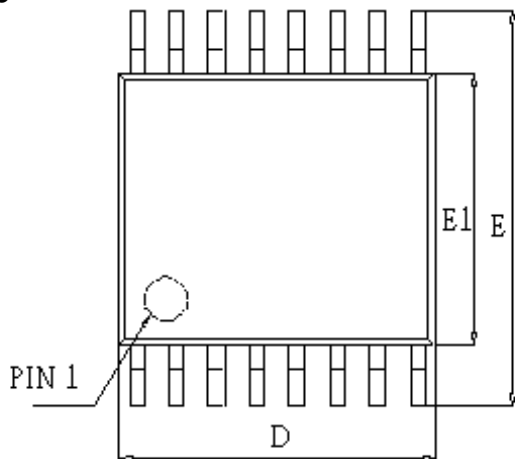
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PACKAGE DIMENSION

TSSOP-16



Symbol	Dimensions In Millimeters			Dimensions In Inches		
	MIN	TYP	MAX	MIN	TYP	MAX
A	1.05	1.10	1.20	0.041	0.043	0.047
A1	0.05	0.10	0.15	0.002	0.004	0.006
A2	-----	1.00	1.05	-----	0.039	0.041
b	0.20	0.25	0.28	0.008	0.010	0.011
C	-----	0.127	-----	-----	0.005	-----
D	4.900	5.075	5.100	0.1930	0.1998	0.2000
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.5	0.170	0.173	0.177
e	-----	0.65	-----	-----	0.026	-----
L	0.5	0.6	0.7	0.020	0.024	0.028
y	-----	-----	0.076	-----	-----	0.003
θ	0°	4°	8°	0°	4°	8°